

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|--------|---|---|------------------|---------|------------------|
| L1 | 212238 | light near emitting near (device or diode or element) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:19 |
| L2 | 24370 | (single-crystal\$4 near silicon) or (monocrystal\$4 near silicon) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:20 |
| L3 | 4067 | (GaN or (gallium near nitride)) same buffer | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:21 |
| L4 | 2486 | (GaN or (gallium near nitride)) same clad\$4 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:23 |
| L5 | 11810 | etch\$3 same buffer | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:25 |
| L6 | 57727 | dicing or cleaving | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:25 |
| L7 | 9 | I1 and I2 and I3 and I4 and I5 and I6 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:26 |
| L8 | 9 | I1 and I2 and I3 and I4 and I6 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:26 |
| L9 | 15 | I1 and I2 and I3 and I4 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/03/21 15:26 |